

PROCEEDINGS OF SPIE

Quantum Sensing and Nanophotonic Devices IX

Manijeh Razeghi
Eric Tournie
Gail J. Brown
Editors

22–26 January 2012
San Francisco, California, United States

Sponsored and Published by
SPIE

Volume 8268

Proceedings of SPIE, 0277-786X, v. 8268

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Author(s), "Title of Paper," in *Quantum Sensing and Nanophotonic Devices IX*, edited by Manijeh Razeghi, Eric Tournie, Gail J. Brown, Proceedings of SPIE Vol. 8268 (SPIE, Bellingham, WA, 2012) Article CID Number.

ISSN 0277-786X
ISBN 9780819489111

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA
Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445
SPIE.org

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